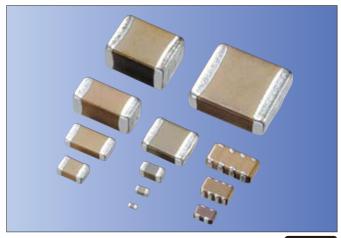
Multilayer Ceramic Chip Capacitors



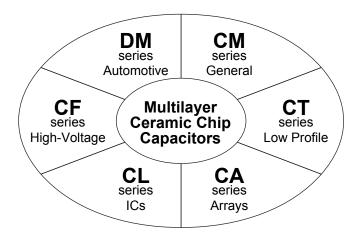
Kyocera's series of Multilayer Ceramic Chip Capacitors are designed to meet a wide variety of needs. We offer a complete range of products for both general and specialized applications, including CM series for general-purpose, CT series for low profile, CA series for arrays, CL series for ICs, CF series for high-voltage, and DM series for automotive.

Features

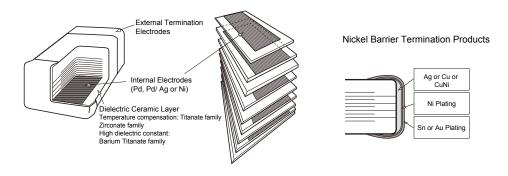
- We have factories worldwide in order to supply our global customer bases quickly and efficiently and to maintain our reputation as one of the highest-volume producers in the industry.
- All our products are highly reliable due to their monolithic structure of high-purity and superfine uniform ceramics and their integral internal electrodes.
- By combining superior manufacturing technology and materials with high dielectric constants, we produce extremely compact components with exceptional specifications.
- Our stringent quality control in every phase of production from material procurement to shipping ensures consistent manufacturing and super quality.
- Kyocera components are available in a wide choice of dimensions, temperature characteristics, rated voltages, and terminations to meet specific configurational requirements.



RoHS Compliant



Structure



Tape and Reel



Bulk Case



Please contact your local AVX, Kyocera sales office or distributor for specifications not covered in this catalog.

Our products are continually being improved. As a result, the capacitance range of each series is subject to change without notice. Please contact an sales representative to confirm compatibility with your application.

Multilayer Ceramic Chip Capacitors



Kyocera Ceramic Chip Capacitors are available for different applications as classified below:

Series	Dielectric Options	Typical Applications	Features	Terminations	Available Size
СМ	COG (NP0) X5R X7R *X6S *X7S Y5V	General purpose	Wide cap range	Nickel barrier	01005, 0201, 0402 0603, 0805, 1206 1210, 1812
СТ	X5R X7R Y5V	IC card (Decoupling)	Low profile	Nickel barrier	0201, 0402, 0603 0805, 1206, 1210
CA	C0G (NP0) X5R, X7R	Digital signal Pass line	Reduction in placing cost	Nickel barrier	0405, 0508
CL	X7S	ICs (Decoupling)	Low inductance	Nickel barrier	0204, 0306
CF	COG (NP0) X7R	High voltage & Power circuits	High voltage 250VDC, 630VDC 1000VDC, 2000VDC 3000VDC, 4000VDC	Nickel barrier	0805, 1206, 1210 1812, 2208, 1808 2220
DM	X7R	Automotive	Thermal shock Resistivity High reliability	Nickel barrier	0603,0805,1206

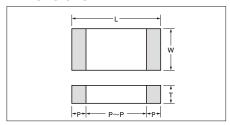
^{*} Option

^{*} Negative temperature coefficient dielectric types are available on request.

Multilayer Ceramic Chip Capacitors



Dimensions



Dimensions and Packaging Quantities

0:	Co	de	Dimension	imension Dimensions (mm) M							antity per reel
Size	JIS	EIA	Code	L	W	Т	P min.	P max.	P to P min.	∮180 Reel	∮330 Reel
02	0402	01005	Α	0.4±0.02	0.2±0.02	0.2±0.02	0.07	0.14	0.13	40kp (P8/1)	- - -
					0.2 0.0					20kp (P8/2) 35kp (P8/1)	50kp (P8/2)
			Α	0.010.00	0.010.00	0.22 max.	0.40	0.00	0.00	15kp (P8/2)	50kp (P8/2)
03	0603	0201	В	0.6±0.03	0.3±0.03	0.3±0.03	0.10	0.20	0.20	35kp (P8/1)	
	0000	020.				0.0=0.00				15kp (P8/2) 35kp (P8/1)	50kp (P8/2)
			С	0.6±0.05	0.3±0.05	0.3±0.05	0.13	0.23	0.19	15kp (P8/2)	50kp (P8/2)
			Α			0.25 max.				30kp (P8/1)	
							_			10kp (P8/2) 30kp (P8/1)	50kp (P8/2)
			В	1.0±0.05	0.5±0.05	0.35 max.				10kp (P8/2)	50kp (P8/2)
			С			0.5±0.05				30kp (P8/1)	- - -
05	1005	0402					0.15	0.35	0.30	10kp (P8/2) 30kp (P8/1)	50kp (P8/2) -
			D	1.0±0.10	0.5±0.10	0.35 max.				10kp (P8/2)	50kp (P8/2)
			Е	1.0±0.10	0.5±0.10	0.5±0.10				30kp (P8/1)	- - -
			_							10kp (P8/2) 30kp (P8/1)	50kp (P8/2) -
			F	1.0±0.15	0.5±0.15	0.5±0.15				10kp (P8/2)	50kp (P8/2)
			Α	1 6+0 10	0.0+0.10	0.55 max.				4kp (P8/4)	10kp (P8/4)
			В	1.6±0.10	0.8±0.10	0.8±0.10				8kp (P8/2) 4kp (P8/4)	20kp (P8/2) 10kp (P8/4)
			С			0.55 max.				8kp (P8/2)	20kp (P8/2)
105	1608	0603		1.6±0.15	0.8±0.15	0.55 max.	0.20	0.60	0.50	4kp (P8/4)	10kp (P8/4) 20kp (P8/2)
			D			0.8±0.15				8kp (P8/2) 4kp (P8/4)	10kp (P8/4)
			Е	1.6±0.2	0.8±0.2	0.55 max.				8kp (P8/2)	20kp (P8/2)
			A	1.0=0.2	0.0±0.2	0.55 max.				4kp (P8/4) 4kp (P8/4)	10kp (P8/4) 10kp (P8/4)
			В			0.95 max.	_			4kp (P8/4)	10kp (P8/4)
			С		1.05±0.10	1.00 max.]			4kp (E8/4)	10kp (E8/4)
			D E	2.0±0.10	1.25±0.10	0.6±0.10 0.85±0.10	_			4kp (P8/4) 4kp (P8/4)	10kp (P8/4) 10kp (P8/4)
0.4	0040	0005	F			1.05±0.10	0.00	0.75	0.70	3kp (E8/4)	10kp (F8/4)
21	2012	0805	G			1.25±0.10	0.20	0.75	0.70	3kp (E8/4)	10kp (E8/4)
			H J	2.0±0.15	1.25±0.15	0.55 max. 0.95 max.				4kp (P8/4) 4kp (P8/4)	10kp (P8/4) 10kp (P8/4)
			K	2.0±0.15	1.25±0.15	1.25±0.15				3kp (E8/4)	10kp (F8/4)
			L	2.0±0.20	1.25±0.20	0.95 max.				4kp (P8/4)	10kp (P8/4)
			M A			1.25±0.20 0.85±0.10				3kp (E8/4) 4kp (P8/4)	10kp (E8/4) 10kp (P8/4)
			В			0.95 max.				4kp (P8/4)	10kp (P8/4)
			С	3.2±0.20	1.6±0.15	1.00 max.				4kp (E8/4)	10kp (E8/4)
316	3216	1206	D E			1.15±0.10 1.25±0.10	0.30	0.85	1.40	3kp (E8/4) 3kp (E8/4)	10kp (E8/4) 10kp (E8/4)
0.0	0210	1200	F			1.6±0.15	0.00	0.00	1.10	2.5kp (E8/4)	5kp (E8/4)
			G	0.010.00	1.010.00	0.95 max.				4kp (P8/4)	10kp (P8/4)
			H J	3.2±0.20	1.6±0.20	1.00 max. 1.6±0.20	-			4kp (E8/4) 2.5kp (E8/4)	10kp (E8/4) 5kp (E8/4)
			Α			1.00 max.				4kp (E8/4)	10kp (E8/4)
			В			1.40 max.				3kp (E8/4)	10kp (E8/4)
32	3225	1210	C D	3.2±0.20	2.5±0.20	1.60 max. 1.6±0.15	0.30	1.00	1.40	2.5kp (E8/4) 2.5kp (E8/4)	5kp (E8/4) 5kp (E8/4)
			E			2.20 max.				2kp (E8/4)	5kp (E8/4)
			F			2.0±0.2				2kp (E8/4)	5kp (E8/4)
10	4500	1000	G A	4.510.00	0.010.00	2.5±0.2 1.6 max.	0.15	0.05	0.00	1kp (E8/4) 2kp (E12/4)	4kp (E8/4) -
42	4520	1808	В	4.5±0.20	2.0±0.20	2.2 max.	0.15	0.85	2.60	2kp (E12/4)	-
			A R			2.0 max. 2.0±0.2	-			1kp (E12/4) 1kp (E12/4)	<u> </u>
40	4500	B C 4510.00	4 5+0 20	3 3+0 00	2.5 max.	0.20	1 10	2.00	0.5kp (E12/4)		
43	4532 1812	D	D 4.5±0.30 3.2±0.20	3.2±0.20	2.5±0.2	0.30	1.10	2.00	0.5kp (E12/4)	-	
			E F			2.8 max. 2.8±0.2	-			0.5kp (E12/4) 0.5kp (E12/4)	
52	5720	2208	A	5.7±0.40	2.0±0.20	2.6±0.2 2.2 max.	0.15	0.85	4.20	2kp (12/4)	
			Α			2.0 max.				1kp (E12/4)	_
55	5750	2220	B C	5.7±0.40	5.0±0.40	2.5 max. 2.8 max.	0.30	1.40	2.50	0.5kp (E12/4) 0.5kp (E12/4)	
				oor rool (kn moons	1	Z.O IIIdX.	1			U.JNP (E12/4)	-

Note: Taping denotes the quantity packaged per reel (kp means 1000 pieces).

Multilayer Ceramic Chip Capacitors Ordering Information



KYOCERA PART NUMBER CM 21 X7R 104 K 50 SERIES CODE -CM = General Purpose CL **ICs** High Voltage CF = CT = Low Profile DM = CA = Arrays Automotive SIZE CODE -SIZE EIA (JIS) SIZE EIA (JIS) SIZE EIA (JIS) 02 = 01005 (0402)32 = 1210 (3225) D11 = 0405 (1014)/2 cap03 = 0201 (0603)42 = 1808 (4520) F12 = 0508 (1220)/4 cap05 = 0402 (1005)43 = 1812 (4532) 52 = 2208 (5720) 105 = 0603 (1608)21 = 0805 (2012)55 = 2220 (5750) 316 = 1206 (3216)**DIELECTRIC CODE** -**CODE EIA CODE** CG = COG (NPO)X7S = X7S (Option) X5R = X5RX6S = X6S (Option) X7R = X7RY5V = Y5VNegative temperature coefficient dielectric types are available on request. CAPACITANCE CODE -Capacitance expressed in pF. Two significant digits plus number of zeros. For Values < 10pF, Letter R denotes decimal point, 100000pF = 1041.5pF = 1R5 $0.1 \mu F = 104$ 0.5pF = R504700pF = 472100μF = 107 TOLERANCE CODE — $A = \pm 0.05 pF$ (option) $D = \pm 0.5pF$ $J = \pm 5\%$ Z = -20 to +80% $B = \pm 0.1pF$ $F = \pm 1pF$ $K = \pm 10\%$ $G = \pm 2\%$ (option) $C = \pm 0.25 pF$ $M = \pm 20\%$ **VOLTAGE CODE** -04 = 4VDC100 = 100VDC1000 = 1000VDC06 = 6.3VDC250 = 250VDC2000 = 2000VDC 10 = 10VDC400 = 400VDC3000 = 3000VDC16 = 16VDC630 = 630VDC4000 = 4000VDC25 = 25VDC35 = 35VDC50 = 50VDCTERMINATION CODE -A = Nickel Barrier/Tin K = Nickel Barrier/ Au PACKAGING CODE -B = BulkL = 13" Reel Taping & 4mm Cavity pitch C = Bulk Cassette (option) H = 7" Reel Taping & 2mm Cavity pitch T = 7" Reel Taping & 4mm Cavity pitch N = 13" Reel Taping & 2mm Cavity pitch Q = 7" Reel Taping & 1mm Cavity pitch OPTION

Thickness max. value is indicated in CT series EX. 125 \rightarrow 1.25mm max.

 $095 \rightarrow 0.95$ mm max.

Multilayer Ceramic Chip Capacitors Temperature Characteristics and Tolerance



Temperature Compensation Type

Dielectric	COG (NPO)	U∆ (N750)	SL
Value (pF)	0 ppm/ °C	-750 ppm/ °C	+350 to -1000ppm/ °C
0.5 to 2.7	CK	UK	SL
3.0 to 3.9	CJ	UJ	SL
4.0 to 9.0	СН	UJ	SL
≥10	CG	UJ	SL

K = ± 250 ppm/ °C, J = ± 120 ppm/ °C, H = ± 60 ppm/ °C, G = ± 30 ppm/ °C e.g. $CG = 0\pm30$ ppm/ $^{\circ}C$

Note: All parts of COG will be marked as "CG" but will conform to the above table.

High Dielectric Constant Type

EIA Dielectric	Temperature Range	∆C max.			
X5R	−55 to 85°C	±150/			
X7R	−55 to 125°C	±15%			
*X7S	−55 to 125°C	+000/			
*X6S	–55 to 105°C	±22%			
Y5V	−30 to 85°C	-82 to +22%			

^{*} option

Available Tolerances

Dielectric materials, capacitance values and tolerances are available in the following combinations only:

EIA Dielectric	Tolerance	Capacitance
	C=±0.25pF	
	D=±0.50pF	*1 <10pF
COG	F=±1pF	
	*3 A=±0.05pF	<0.5pF
Cod	B=±0.1pF	≤5pF
	*3 G=±2%	/10sE
	J=±5%	≥10pF
	K=±10%	E12 Series
*3 X6S X5R	*2 K=±10%	*4 E3 Series
*3 X7S X7R	M=±20%	ES Series
Y5V	Z=-20% to +80%	E3 Series

E Standard Number

E3	E 6	E12	E24 (C	option)
	1.0	1.0	1.0	1.1
1.0	1.0	1.2	1.2	1.3
1.0	1.5	1.5	1.5	1.6
	1.5	1.8	1.8	2.0
	2.2	2.2	2.2	2.4
2.2	2.2	2.7	2.7	3.0
2.2	3.3	3.3	3.3	3.6
	3.3	3.9	3.9	4.3
	4.7	4.7	4.7	5.1
4.7	4.7	5.6	5.6	6.2
4.7	6.8	6.8	6.8	7.5
	0.0	8.2	8.2	9.1

^{*1} Nominal values below 10pF are available in the standard values of 0.5pF, 1.0pF, 1.5pF, 2.0pF, 3.0pF, 4.0pF, 5.0pF, 6.0pF, 7.0pF, 8.0pF, 9.0pF *2 J = ±5% for X7R (X5R) is available on request.

^{*4} E6 series is available on request.



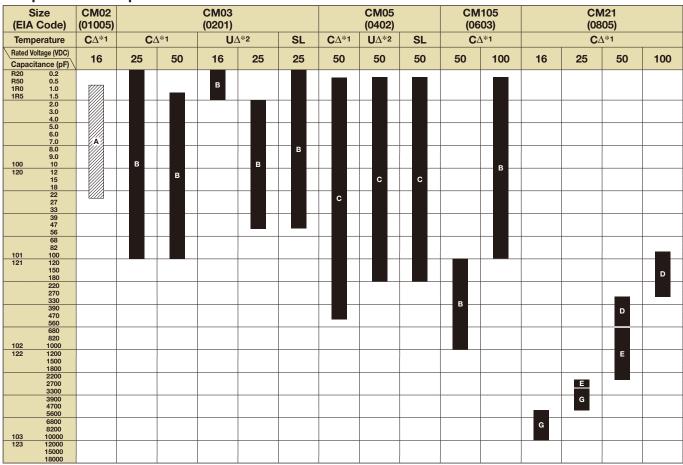
Features

We offer a diverse product line ranging from ultra-compact (0.4×0.2mm) to large (4.5×3.2mm) components configured for a variety of temperature characteristics, rated voltages, and packages. We offer the choice and flexibility for almost any applications.

Applications

This standard type is ideal for use in a wide range of applications, from commercial to industrial equipment.

Temperature Compensation Dielectric



[•] E24 sereis is available on request.

Optional Spec.

*1: CG,CH,CJ,CK

*2: UJ,UK

Alphabets in capacitance chart denote dimensions. Please refer to the below table for detail.

(Example)

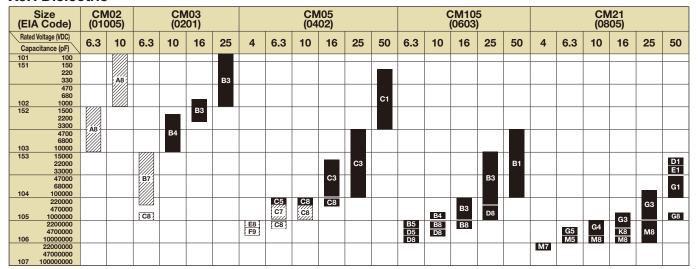
In case of "B" for CM03;

L : 0.6±0.03mm W: 0.3±0.03mm T: 0.3±0.03mm

Size	Size	Dir	mension (m	nm)		
Size	Code	L	W	Т		
02	Α	0.4±0.02	0.2±0.02	0.2±0.02		
03	В	0.6±0.03	0.3±0.03	0.3±0.03		
05	С	1.0±0.05	0.5±0.05	0.5±0.05		
105	В	1.6±0.10	0.8±0.10	0.8±0.10		
	D			0.6±0.10		
21	E	2.0±0.10	1.25±0.10	0.85±0.10		
	G			1.25±0.10		



X5R Dielectric



(EI	Size A Code)			CM31 (1206)				CM32 (1210)					CM43 (1812)	
	d Voltage (VDC) acitance (pF)	6.3	10	16	25	50	4	6.3	10	16	25	50	6.3	50
105	220000 470000 1000000				D3	D1					В3	B1 F1		
106	2200000 4700000 10000000	F5	F4	F3	F3 J8				F4	C3	F3 G3 G8			D1
107	22000000 4700000 10000000	J5	J8	J8			G5	G5	G4	G3	G8		F5	

- E6 series is standard.
- E3 series is standard for the size 316 and larger.
- E12 series is available on request.
- Optional Spec.

Two digits alphanumerics in capacitance chart denote dimensions and tan $\delta.$ Please refer to the below table for detail.

(Example)

In case of "B2" for CM03; L: 0.6±0.03mm W: 0.3±0.03mm T: 0.3±0.03mm Tan δ: 3.5% max.

Size	Size	Dir	nension (m	ım)
Size	Code	L	W	Т
02	Α	0.4±0.02	0.2±0.02	0.2±0.02
03	В	0.6±0.03	0.3±0.03	0.3±0.03
03	С	0.6±0.05	0.3±0.05	0.3±0.05
	С	1.0±0.05	0.5±0.05	0.5±0.05
05	E	1.0±0.10	0.5±0.10	0.5±0.10
	F	1.0±0.15	0.5±0.15	0.5±0.15
105	В	1.6±0.10	0.8±0.10	0.8±0.10
105	D	1.6±0.15	0.8±0.15	0.8±0.15
	D	2.0±0.10	1.25±0.10	0.6±0.10
	E	2.0±0.10	1.25±0.10	0.85±0.10
21	G	2.0±0.10	1.25±0.10	1.25±0.10
	K	2.0±0.15	1.25±0.15	1.25±0.15
	М	2.0±0.20	1.25±0.20	1.25±0.20

Size	Size	Dir	nension (m	ım)		
Size	Code	L	W	Т		
	D	3.2±0.20	1.6±0.15	1.15±0.10		
316	F	3.2±0.20	1.6±0.15	1.6±0.15		
	J	3.2±0.20	1.6±0.20	1.6±0.20		
	В	3.2±0.20	2.5±0.20	1.40 max.		
32	С	3.2±0.20	2.5±0.20	1.60 max.		
32	F	3.2±0.20	2.5±0.20	2.0±0.2		
	G	3.2±0.20	2.5±0.20	2.5±0.2		
43	D	4.5±0.30	3.2±0.20	2.5±0.2		
43	F	4.5±0.30	3.2±0.20	2.8±0.2		

$\begin{array}{c} \text{Tan } \delta \\ \text{Code} \end{array}$	Tan δ						
1	2.5% max.						
2	3.5% max.						
3	5.0% max.						
4	7.0% max.						
5	7.5% max.						
7	10.0% max.						
8	12.5% max.						
9	20.0% max.						



X7R Dielectric

	Size (Code)	CM02 (01005)		CM03 (0201)			CM05 (0402)				CM (06						CN (08			
	Voltage (VDC)	10	10	16	25	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100
101 151	100 150 220	A8			B2															
102	330 470 680 1000	A8		B2				C1						B1						
152	1500 2200 3300	7777	В3																	
103	4700 6800 10000		БЗ			C2	C2													D1 E1
153	15000 22000 33000 47000											B2 -	В1						D1 E1	G1
104	68000 100000 220000					C8	C8			В3	B2							G2	G1	
105	470000 1000000 2200000								D8	B8	B8	D8				G3	G2 G8	G8 M8		
106	4700000 10000000 22000000								D8						M8	M8	M8	IVIS		

	Size (Code)				316 06)					CM32 (1210)			CN (18	143 12)
	Voltage (VDC)	6.3	10	16	25	50	100	10	16	25	50	100	50	100
104	47000 100000					A1	D1 F1					B1		
105	220000 470000 1000000			D2	D2 F2	D1				B2	B1 F1	F1 G1	В1	D1
106	2200000 4700000 10000000 22000000	J8	J8	J8	J8			G8	G2 G8	G8			D1	

Optional Spec.

Two digits alphanumerics in capacitance chart denote dimensions and tan $\delta.\,$ Please refer to the below table for detail.

(Example)
In case of "B3" for CM03;
L: 0.6±0.03mm
W: 0.3±0.03mm
T: 0.3±0.03mm Tan δ : 5.0% max.

Size	Size	Dir	mension (m	ım)
Size	Code	L	W	Т
02	Α	0.4±0.02	0.2±0.02	0.2±0.02
03	В	0.6±0.03	0.3±0.03	0.3±0.03
05	С	1.0±0.05	0.5±0.05	0.5±0.05
105	В	1.6±0.10	0.8±0.10	0.8±0.10
105	D	1.6±0.15	0.8±0.15	0.8±0.15
	D			0.6±0.10
21	E	2.0±0.10	1.25±0.10	0.85±0.10
21	G			1.25±0.10
	М	2.0±0.20	1.25±0.20	1.25±0.20
	Α			0.85±0.10
316	D	3.2±0.20	1.6±0.15	1.15±0.10
310	F			1.6±0.15
	J	3.2±0.20	1.6±0.20	1.6±0.20
	В			1.40 max.
32	F	3.2±0.20	2.5±0.20	2.0±0.2
	G			2.5±0.2
43	В	4.5±0.30	3.2±0.20	2.0±0.2
73	D	4.5±0.50	0.2.0.20	2.5±0.2

Tan δ Code	Tan δ			
1	2.5% max.			
2	3.5% max.			
3	5.0% max.			
8	12.5% max.			



Y5V Dielectric

	Size A Code)	CN (02				105 ·02)				105 03)				121 (05)			CM316 (1206)			CM32 (1210)	
	Voltage (VDC)	6.3	10	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	10	16	25
102 472	1000 2200 4700		В8				СЗ														
103 473	10000 22000 47000	В8			C6	C3	Co			D 0	В3										
104 474	100000 220000 470000			C8					В6	B3 B4			E6	D3 E3 G3	G3						
105 475	1000000 2200000 4700000							B8				G8	G6	G4			D6	D4			
106 476	10000000 22000000 47000000											G9				F8 F9	F6		F8	C6	C6

Two digits alphanumerics in capacitance chart denote dimensions and $\tan\delta$. Please refer to the below table for detail.

Size

F

С

F

32

(Example)

In case of "B8" for CM03;

 $\begin{array}{l} L \ : \ 0.6 \pm 0.03 mm \\ W : \ 0.3 \pm 0.03 mm \\ T \ : \ 0.3 \pm 0.03 mm \\ Tan \ \delta : \ 12.5 \% \ max. \end{array}$

	Code	L	W	Т	
03 B		0.6±0.03	0.3±0.03	0.3±0.03	
05	С	1.0±0.05	0.5±0.05	0.5±0.05	
105 B		1.6±0.10	0.8±0.10	0.8±0.10	
	D	2.0±0.10	1.25±0.10	0.6±0.10	
21	E	2.0±0.10	1.25±0.10	0.85±0.10	
	G	2.0±0.10	1.25±0.10	1.25±0.10	
040	D	3.2±0.20	1.6±0.15	1.15±0.10	

3.2±0.20

3.2±0.20

3.2±0.20

Dimension (mm)

1.6±0.15

2.5±0.20

2.5±0.20

1.6±0.15

1.60 max.

2.0±0.2

$\begin{array}{c} \text{Tan } \delta \\ \text{Code} \end{array}$	Tan δ
3	5.0% max.
4	7.0% max.
6	9.0% max.
8	12.5% max.
9	16.0% max.



Test Conditions and Specifications for Temperature Compensation Type (C \triangle to U \triangle • SL Characteristics) CM/ CT/ CF/ CA Series

Test	Items	Specifications	Test Conditions			
Capacitance V	/alue (C)	Within tolerance	Capacitance Frequency Volt			
Q		C≥30pF : Q≥1000 C<30pF : Q≥400+20C	C≤1000pF 1MHz±10% C>1000pF 1kHz±10% 0.5 to 5Vrms			
Insulation Resistance (IR)		Over 10000M Ω or 500M Ω • μ F, whichever is less	Measured after the rated voltage is applied for 1 minute at room ambient. For the rated voltage of over 630V, apply 500V for 1 minute at room ambient. The charge and discharge current of the capacit must not exceed 50mA.			
Dielectric Res	istance	No problem observed	Apply 3 times of the rated voltage for 1 to 5 seconds Apply 1.5 times when the rated voltage is 250V or ov Apply 1.2 times when the rated voltage is 630V or ov The charge and discharge current of the capaci must not exceed 50mA.			
Appearance		No problem observed	Microscope (10× magnification)			
Termination St	trength	No problem observed	Apply a sideward force of 500g (5N) to a PCB-mounted sample. Apply 2N for 0201, and 1N for 01005 size.			
Bending Stren	gth	No significant damage at 1mm bent	Glass epoxy PCB: Fulcrum spacing: 90mm, duration time 10 seconds.			
Vibration	Appearance	No problem observed	Vibration frequency: 10 to 55 (Hz)			
Test	ΔC	Within Tolerance	Amplitude: 1.5mm Sweeping condition: 10→55→10Hz/ 1 minute in			
	Q	C≥30pF : Q≥1000 C<30pF : Q≥400+20C	Y and Z Directions: 2 hours each, 6 hours total.			
Soldering	Appearance	No problem observed	Soak the sample in 260°C±5°C solder for 10±0.5			
Heat Resistance	ΔC	Within ±2.5% or ±0.25pF, whichever is larger	seconds and place in room ambient, and measure after 24±2 hours.			
	Q	C≥30pF : Q≥1000 C<30pF : Q≥400+20C	(Pre-heating conditions) Order Temperature Time			
	IR	Over 10000M Ω or 500M Ω • μ F whichever is less	1 80 to 100°C 2 minutes			
	Withstanding Voltage	Resist without problem	2 150 to 200°C 2 minutes The charge and discharge current of the capacit must not exceed 50mA for IR and withstanding voltage measurement.			
Solderablity		Solder coverage : 90% min.	Sne3 Solder 235±5°C 2±0.5 sec. Sn-3Ag-0.5Cu 245±5°C 3±0.5 sec.			
Temperature	Appearance	No problem observed	(Cycle)			
Cycle	ΔC	Within $\pm 2.5\%$ or ± 0.25 pF, whichever is larger	Room temperature (3min.)→			
	Q	C≥30pF : Q≥1000 C<30pF : Q≥400+20C	Lowest operation temperature (30min.)→ Room temperature (3min.)→			
	IR	Over 10000M Ω or 500M Ω • $\mu\text{F},$ whichever is less	Highest operation temperature(30min.)			
	Withstanding Voltage	Resist without problem	After 5 cycles, measure after 24±2 hours. The charge and discharge current of the capacit must not exceed 50mA for IR and withstanding voltage measurement.			
Load	Appearance	No problem observed	After applying rated voltage for 500+12/ –0 hour			
Humidity Test			in pre-condition at 40°C±2°C, humidity 90 to			
Humidity Test	ΔC	Within ±7.5% or ±0.75pF, whichever is larger				
_	ΔC Q	Within ±7.5% or ±0.75pF, whichever is larger C≥30pF : Q≥200 C<30pF : Q≥100+10C/3	 95%RH, allow parts to stabilize for 24±2 hours, room temperature before measurement. The charge and discharge current of the capacit 			
Test (Except CF		C≥30pF : Q≥200	95%RH, allow parts to stabilize for 24±2 hours, room temperature before measurement.			
Test (Except CF	Q	C≥30pF : Q≥200 C<30pF : Q≥100+10C/3	95%RH, allow parts to stabilize for 24±2 hours, room temperature before measurement. The charge and discharge current of the capacit must not exceed 50mA for IR measurement.			
Test (Except CF Series) High- Temperature	Q IR	C \geq 30pF : Q \geq 200 C $<$ 30pF : Q \geq 100+10C/ 3 Over 500M Ω or 25M Ω • μ F, whichever is less	95%RH, allow parts to stabilize for 24±2 hours, room temperature before measurement. The charge and discharge current of the capacit must not exceed 50mA for IR measurement. After applying twice the rated voltage at the temperature of 125±3°C for 1000+12/ –0 hours,			
Test (Except CF Series)	Q IR Appearance	C \geq 30pF : Q \geq 200	95%RH, allow parts to stabilize for 24±2 hours, room temperature before measurement. The charge and discharge current of the capacit must not exceed 50mA for IR measurement. After applying twice the rated voltage at the			



Test Conditions and Specifications for High Dielectric Type (X5R, X7R) CM/ CT/ CA Series

Test	Items	Specifications	Test Conditions			
Capacitance \	/alue (C)	Within tolerance	Measure after heat treatment			
Tanδ (%)		Refer to capacitance chart	Capacitance Frequency Volt C≤10μF 1kHz±10% 1.0±0.2Vrms C>10μF 120Hz±10% 0.5±0.2Vrms			
Insulation Res	sistance (IR)	Over 10000M Ω or 500M Ω • μ F, whichever is less	Measured after the rated voltage is applied for 1 minute at room ambient. The charge and discharge current of the capacitor must not exceed 50mA.			
Dielectric Res	istance	No problem observed	Apply 2.5 times of the rated voltage for 1 to 5 seconds. The charge and discharge current of the capacitor must not exceed 50mA.			
Appearance		No problem observed	Microscope (10× magnification)			
Termination S	trength	No problem observed	Apply a sideward force of 500g (5N) to a PCB-mounted sample. note: 2N for 0201 size in for 01005 size. Exclude CT series with thickness of less than 0.66mm.			
Bending Stren	gth	No significant damage at 1mm bent	Glass epoxy PCB: Fulcrum spacing: 90mm, duration time 10 seconds. Exclude CT series with thickness of less than 0.66mm.			
Vibration	Appearance	No problem observed	Take the initial value after heat treatment.			
Test	ΔC	Within tolerance	Vibration frequency: 10 to 55 (Hz) Amplitude: 1.5mm			
	Tanδ (%)	Within tolerance	Sweeping condition: 10→55→10Hz/1 minute in X, Y and Z Directions: 2 hours each, 6 hours total.			
Soldering	Appearance	No problem observed	Take the initial value after heat treatment.			
Heat Resistance	ΔC	Within ±7.5%	Soak the sample in 260°C±5°C solder for 10±0.5 seconds and place in room ambient, and measure			
110010101100	Tanδ (%)	Within tolerance	after 24±2 hours.			
	IR	Over $10000M\Omega$ or $500M\Omega$ • μF , whichever is less	(Pre-heating conditions) Order Temperature Time			
	Withstanding Voltage	Resist without problem	1 80 to 100°C 2 minute 2 150 to 200°C 2 minute The charge and discharge current of the capacitor mus exceed 50mA for IR and withstanding voltage measurement			
Solderablity		Solder coverage : 90% min.	Soaking condition Sn63 Solder 235±5°C 2±0.5 sec. Sn-3Ag-0.5Cu 245±5°C 3±0.5 sec.			
Temperature	Appearance	No problem observed	Take the initial value after heat treatment.			
Cycle	ΔC	Within ±7.5%	(Cycle) Room temperature (3min.)→			
	Tanδ (%)	Within tolerance	Lowest operation temperature (30min.)→			
	IR	Over $10000M\Omega$ or $500M\Omega$ • μ F, whichever is less	Room temperature (3min.)→ Highest operation temperature(30min.)			
	Withstanding Voltage	Resist without problem	After 5 cycles, measure after 24±2 hours. The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.			
Load	Appearance	No problem observed	Take the initial value after voltage treatment.			
Humidity	ΔC	Within ±12.5%	After applying rated voltage for 500+12/ –0 hours in pre-condition at 40°C±2°C, humidity 90 to			
Test	Tanδ (%)	200% max. of initial value	95%RH, allow parts to stabilize for 24±2 hours, at			
	IR	Over 500M Ω or 25M Ω • μ F, whichever is less	room temperature before measurement. The charge and discharge current of the capacitor must not exceed 50mA for IR measurement.			
High-	Appearance	No problem observed	Take the initial value after voltage treatment.			
Temperature	ΔC	Within ±12.5%	After applying twice the rated voltage at the highest operation temperature for 1000+12/ –0 hours,			
with Loading	Tanδ (%)	200% max. of initial value	measure the sample after 24±2 hours.			
Louding	IR	Over 1000M Ω or 50M Ω • μ F, whichever is less	The charge and discharge current of the capacitor must not exceed 50mA for IR measurement. Apply 1.5 times when the rated voltage is 10V or less. Applied voltages for respective products are indicated in the below chart.			

Pre-	Heat Keep specimen at 150+0/ −10°C for 1 hour, leave specimen at room ambient for 24±2 hours.					
treatment	Voltage	Apply the same test condition for 1 hour, then leave the specimen at room ambient for 24±2 hours.				

High-temperature with Loading Applied Voltage (Rated Voltage \times \square)

	·	0 11 0 1 0 -7
Applied Voltage	Rated Voltage	Products
×1.3	6.3V	CM105X5R475, CM316X5R476
×1.3	0.30	CT05X5R104, CT21X5R106
	16)/	CM105X7R474-105, CM21X7R105-475, CM316X7R475-106, CM32X7R106-226, CM05X5R224, CM105X5R225, CM21X5R475-106, CM316X5R226
	16V	CT105X5R105, CT21X5R225-475, CT316X5R106
V4 E	25V	CM105X7R474, CM21X7R105-225, CM316X7R475, CM32X7R106, CM105X5R474-105, CM21X5R225-106, CM316X5R106, CM32X5R106-226
×1.5	250	CT316X5R225-106
	E01/	CM21X5R105
	50V	CT21X5R225, CT316X5R225-475



Test Conditions and Specifications for High Dielectric Type (Y5V) CM/ CT/ CA Series

Test	Items	Specifications	Test Conditions			
Capacitance \	/alue (C)	Within tolerance	Measure after heat treatment			
Tanδ (%)		Refer to capacitance chart	Frequency Volt 1kHz±10% 1.0±0.2Vrms			
Insulation Resistance (IR)		Over 10000M Ω or 500M Ω • μ F, whichever is less	Measured after the rated voltage is applied for 1 minute at room ambient.			
Dielectric Res	istance	No problem observed	Apply 2.5 times of the rated voltage for 1 to 5 seconds. The charge and discharge current of the capacitor must not exceed 50mA.			
Appearance		No problem observed	Microscope (10× magnification)			
Termination S	trength	No problem observed	Apply a sideward force of 500g (5N) to a PCB-mounted sample. note: 2N for 0201 size in for 01005 size. Exclude CT series with thickness of less than 0.66mm.			
Bending Stren	ngth	No significant damage at 1mm bent	Glass epoxy PCB: Fulcrum spacing: 90mm, duration time 10 seconds. Exclude CT series with thickness of less than 0.66mm.			
Vibration	Appearance	No problem observed	Take the initial value after heat treatment.			
Test	ΔC	Within tolerance	Vibration frequency: 10 to 55 (Hz) Amplitude: 1.5mm			
	Tan δ (%)	Within tolerance	Amplitude: 1.5mm Sweeping condition: 10→55→10Hz/ 1 minute in X, Y and Z Directions: 2 hours each, 6 hours total.			
Soldering	Appearance	No problem observed	Take the initial value after heat treatment.			
Heat Resistance	ΔC	Within ±20%	Soak the sample in 260°C±5°C solder for 10±0.5 seconds and place in room ambient, and measure after 24±2 hours.			
	Tanδ (%)	Within tolerance				
	IR	Over 10000M Ω or 500M Ω • μ F, whichever is less	(Pre-heating conditions) Order Temperature Time			
	Withstanding Voltage	Resist without problem	1 80 to 100°C 2 minutes 2 150 to 200°C 2 minutes The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.			
Solderablity		Solder coverage : 90% min.	Soaking condition Sn63 Solder 235±5°C 2±0.5 sec. Sn-3Ag-0.5Cu 245±5°C 3±0.5 sec.			
Temperature	Appearance	No problem observed	Take the initial value after heat treatment.			
Cycle	ΔC	Within ±20%	(Cycle) Room temperature (3min.)→			
	Tanδ (%)	Within tolerance	Lowest operation temperature (30min.)→			
	IR	Over 10000M Ω or 500M Ω • μ F, whichever is less	Room temperature (3min.)→ Highest operation temperature(30min.)			
	Withstanding Voltage	Resist without problem	After 5 cycles, measure after 24±2 hours. The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.			
Load	Appearance	No problem observed	Take the initial value after voltage treatment.			
Humidity Test	ΔC	Within ±30%	After applying rated voltage for 500+12/ –0 hours in pre-condition at 40°C±2°C, humidity 90 to			
.550	Tanδ (%)	150% max. of initial value	95%RH, allow parts to stabilize for 24±2 hours, at			
	IR	Over 500M Ω or 25M Ω • μ F, whichever is less	room temperature before measurement. The charge and discharge current of the capacitor must not exceed 50mA for IR measurement.			
High-	Appearance	No problem observed	Take the initial value after voltage treatment.			
Temperature with	ΔC	Within ±30%	After applying twice the rated voltage at the highest operation temperature for 1000+12/ –0 hours,			
Loading	Tanδ (%)	150% max. of initial value	measure the sample after 24±2 hours.			
	IR	Over 1000M Ω or 50M Ω • μ F, whichever is less	The charge and discharge current of the capacitor must not exceed 50mA for IR measurement.			
Pre- treatment	Heat Voltage	Keep specimen at 150+0/ -10°C for 1 hour, leave specimen at Apply the same test condition for 1 hour, then leave the specimen				
	,	1 1 1 2 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1				

treatment

Voltage



Test Conditions and Specifications for High Dielectric Type (X7R) CF Series

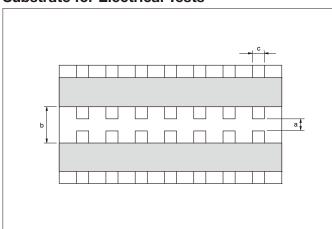
Test Items		Specifications	Test Conditions				
Capacitance \	/alue (C)	Within tolerance	Measure after heat treatment				
Tanδ (%)		Within ±2.5%	CapacitanceFrequencyVoltC≤10μF1kHz±10%1.0±0.2Vrms				
Insulation Resistance (IR)		Over 10000M Ω or 500M Ω • μ F, whichever is less Over 100M Ω • μ F for CF316X7R104/ 250V and CF43X7R474/ 250V CF55X7R105/ 250V and CF55X7R224/ 630V	Measured after the rated voltage is applied for 1 minute at room ambient. Measured after the 500V is applied for 1 minute at room ambient for the rated voltage over 630V. The charge and discharge current of the capacitor must not exceed 50mA.				
Dielectric Res	istance	No problem observed	Apply 1.5 times when the rated voltage is 250V or over, apply 1.2 times when the rated voltage is 630V or over for 1 to 5 seconds. The charge and discharge current of the capacitor must not exceed 50mA.				
Appearance		No problem observed	Microscope (10× magnification)				
Termination S	trength	No problem observed	Apply a sideward force of 500g (5N) to a PCB-mounted sample.				
Bending Stren	igth	No significant damage at 1mm bent	Glass epoxy PCB: Fulcrum spacing: 90mm, duration time 10 seconds.				
Vibration	Appearance	No problem observed	Take the initial value after heat treatment.				
Test	ΔC	Within tolerance	Vibration frequency: 10 to 55 (Hz) Amplitude: 1.5mm				
	Tanδ (%)	Within tolerance	Sweeping condition: $10 \rightarrow 55 \rightarrow 10$ Hz/ 1 minut in X, Y and Z Directions: 2 hours each, 6 hours total.				
Soldering	Appearance	No problem observed	Take the initial value after heat treatment.				
Heat Resistance	ΔC	Within ±7.5%	Soak the sample in 260°C±5°C solder for 10±0.5 seconds and place in room ambient,				
	Tanδ (%)	Within tolerance	and measure after 24±2 hours. (Pre-heating conditions)				
	IR	Over $10000M\Omega$ or $500M\Omega$ • μ F, whichever is less Over $100M\Omega$ • μ F for CF316X7R104/ 250V and CF43X7R474/ 250V CF55X7R105/ 250V and CF55X7R224/ 630V	OrderTemperatureTime180 to 100°C2 minutes				
	Withstanding Voltage	Resist without problem	2 150 to 200°C 2 minutes The charge and discharge current of the capacitor must not exceed 50mA for IR and withstanding voltage measurement.				
Solderablity		Solder coverage : 90% min.	Soaking condition Sn63 Solder 235±5°C 2±0.5 sec. Sn-3Ag-0.5Cu 245±5°C 3±0.5 sec.				
Temperature	Appearance	No problem observed	Take the initial value after heat treatment.				
Cycle	ΔC	Within ±7.5%	(Cycle) Room temperature (3min.)→				
	Tanδ (%)	Within tolerance	Lowest operation temperature (30min.)→				
	IR	Over 10000M Ω or 500M Ω • μ F, whichever is less Over 100M Ω • μ F for CF316X7R104/ 250V and CF43X7R474/ 250V CF55X7R105/ 250V and CF55X7R224/ 630V	Room temperature (3min.)→ Highest operation temperature(30min.) After 5 cycles, measure after 24±2 hours. The charge and discharge current of the				
	Withstanding Voltage	Resist without problem	capacitor must not exceed 50mA for IR and withstanding voltage measurement.				
High- Appearance		No problem observed	Take the initial value after voltage treatment.				
Temperature with	ΔC	Within ±12.5%	After applying specified voltage at the highest operation temperature for 1000+12/ –0 hours,				
Loading	Tanδ (%)	200% max. of initial value	then measure the sample after 24±2 hours.				
	IR	Over 1000M Ω or 50M Ω • μ F, whichever is less	The applied voltage shall be; 1.5 times the rated voltage when the rated voltage is 250V or over. 1.2 times when the rated voltage is 630V or over. The charge and discharge current of the capacitor must not exceed 50mA for IR measurement.				
Pre-	Heat	Keep specimen at 150+0/ -10°C for 1 hour, leave specimen at	room ambient for 24±2 hours.				

Apply the same test condition for 1 hour, then leave the specimen at room ambient for 24±2 hours.



(Unit: mm)

Substrate for Electrical Tests

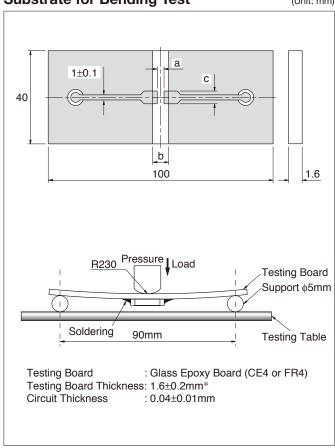


Size (EIA Code)	а	b	С
02 (01005)	0.15	0.50	0.20
03 (0201)	0.26	0.92	0.32
05 (0402)	0.4	1.4	0.5
105 (0603)	1.0	3.0	1.2
21 (0805)	1.2	4.0	1.65
316 (1206)	2.2	5.0	2.0
32 (1210)	2.2	5.0	2.9
42 (1808)	3.5	7.0	3.7
43 (1812)	3.5	7.0	3.7
52 (2208)	4.5	8.0	5.6
55 (2220)	4.5	8.0	5.6

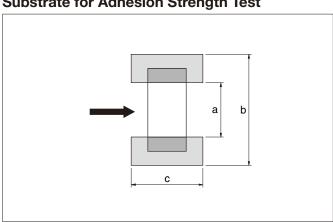
Substrate for Bending Test

* 02, 03, 05 and array: 0.8 ± 0.1 mm

(Unit: mm)



Substrate for Adhesion Strength Test

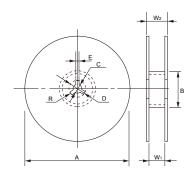


Multilayer Ceramic Chip Capacitors Packaging Options

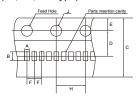


Tape and Reel

• Reel

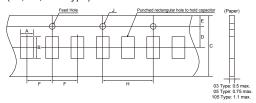


F=1mm (02, 03, 05 Type)

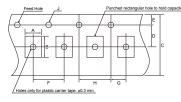


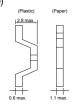


F=2mm (03, 05, 105 Type)

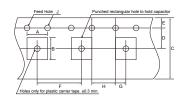


F=4mm (105, D11, F12, 21, 316, 32, 42, 52 Type)





F=8mm (43, 55 Type)





Reel

(Unit: mm)

Code Reel	Α	В	С	D
7-inch Reel (CODE: T, H, Q)	180 +0 -2.0	φ60 min.	13±0.5	21±0.8
13-inch Reel (CODE: L, N)	330±2.0	φ100±1.0	13±0.5	∠1±0.8
Code Reel	E	W 1	W ₂	R
7-inch Reel (CODE: T, H, Q)	0.010.5	10.0±1.5	10.5	1.0
13-inch Reel (CODE: L, N)	2.0±0.5	9.5±1.0	16.5 max.	1.0

^{*} Carrier tape width 8mm.

Carrier Tape

(Unit: mm)

Size (EIA Code)	Α	В	F
02 (01005)	0.25±0.03	0.45±0.03	2.0±0.05
03 (0201)*	0.37±0.03	0.67±0.03	2.0±0.05
05 (0402)	0.65±0.1	1.15±0.1	2.0±0.05
105 (0603)	1.0±0.2	1.8±0.2	4.0±0.1
21 (0805)	1.5±0.2	2.3±0.2	4.0±0.1
316 (1206)	2.0±0.2	3.6±0.2	4.0±0.1
32 (1210)	2.9±0.2	3.6±0.2	4.0±0.1
42 (1808)	2.4±0.2	4.9±0.2	4.0±0.1
43 (1812)	3.6±0.2	4.9±0.2	8.0±0.1
52 (2208)	2.4±0.2	6.0±0.2	4.0±0.1
55 (2220)	5.3±0.2	6.0±0.2	8.0±0.1
D11 (0405)	1.15±0.2	1.55±0.2	4.0±0.1
F12 (0508)	1.5±0.2	2.3±0.2	4.0±0.1

^{*} Option : A : 0.39 ± 0.03 , B : 0.69 ± 0.03

(Unit: mm)

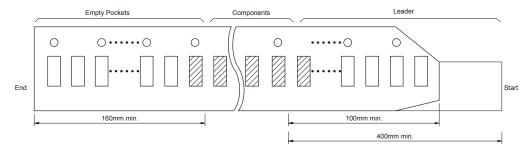
F	Carrier Tape	С	D	E	G	Н	J
1.0 0.05	1mm Paper	8.0 +0.3/ -0.1				4.0 ±0.05	
2.0 0.05	8mm	0.0	3.5 ±0.05				
	Paper	8.0 ±0.3	±0.05	1.75	2.0		1.5
4.0 :0.1	8mm Plastic			±0.1	±0.05	4.0 ±0.1	+0.1/ -0
8.0 -0.1	12mm Plastic	12.0 ±0.3	5.5 ±0.05				

For size 42 (1808) or over, Tape width 12mm and W1: 14±1.5, W2: 18.4mm max.

Multilayer Ceramic Chip Capacitors Packaging Options



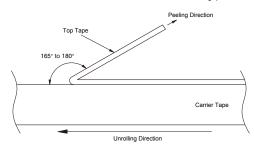
Detail of leader and trailer



Adhesive tape

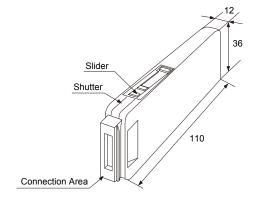
- 1) The exfoliative strength when peeling off the top tape from the carrier tape by the method of the following figure shall be 0.1-0.7N.
- 2) When the top tape is peeled off, the adhesive stays on the top tape.
- 3) Chip capacitors will be in a state free without being stuck on the thermal adhesive tape.

Exfoliating angle: 165 to 180 degrees to the carrier tape. Exfoliating speed: 300 mm/min.



(Unit: mm)

Bulk Case



Package quantity

Size Code	Thickness (mm)	Package quantity (pcs.)
05	0.5	50,000
105	0.8	15,000
21	1.25	5,000

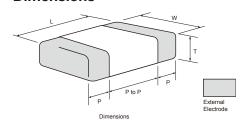
Note: Please check us for bulk case applicable products.

Bulk Case

Size	EIA	JIS			Dimension	ons (mm)		
Code	CODE	CODE	L	W	Т	P min.	P max.	P to P min.
05	0402	1005	1.0±0.05	0.5±0.05	0.5±0.05	0.15	0.35	0.30
105	0603	1608	1.6±0.07	0.8±0.07	0.8±0.07	0.20	0.60	0.50
21	0805	2012	2.0±0.1	1.25±0.1	1.25±0.1	0.20	0.75	0.70

Note: Regarding support for Bulk cases, please contact us for further information.

Dimensions



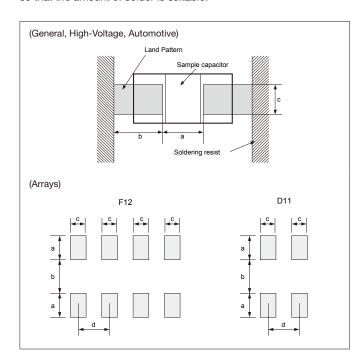
Multilayer Ceramic Chip Capacitors Surface Mounting Information



Dimensions for recommended typical land

Since the amount of solder (size of fillet) to be used has direct influence on the capacitor after mounting, the sufficient consideration is necessary.

When the amounts of solder is too much, the stress that a capacitor receives becomes larger. It may become the cause of a crack in the capacitor. When the land design of printed wiring board is considered, it is necessary to set up the form and size of land pattern so that the amount of solder is suitable.



Design of printed circuit and Soldering

The recommended fillet height shall be 1/2 to 1/3 of the thickness of capacitors. When mounting two or more capacitors in the common land, it is necessary to separate the land with the solder resist strike so that it may become the exclusive land of each capacitor.

General, High-Voltage

(Unit: mm)

Size (EIA Code)	L×W	а	b	С
02 (01005)	0.4×0.2	0.13 to 0.20	0.12 to 0.18	0.20 to 0.23
03 (0201)	0.6×0.3	0.20 to 0.30	0.25 to 0.35	0.30 to 0.40
05 (0402)	1.0×0.5	0.30 to 0.50	0.35 to 0.45	0.40 to 0.60
105 (0603)	1.6×0.8	0.70 to 1.00	0.80 to 1.00	0.60 to 0.80
21 (0805)	2.0×1.25	1.00 to 1.30	1.00 to 1.20	0.80 to 1.10
316 (1206)	3.2×1.6	2.10 to 2.50	1.10 to 1.30	1.00 to 1.30
32 (1210)	3.2×2.5	2.10 to 2.50	1.10 to 1.30	1.90 to 2.30
42 (1808)	4.5×2.0	2.50 to 3.20	1.80 to 2.30	1.50 to 1.80
43 (1812)	4.5×3.2	2.50 to 3.20	1.80 to 2.30	2.60 to 3.00
52 (2208)	5.7×2.0	4.20 to 4.70	2.00 to 2.50	1.50 to 1.80
55 (2220)	5.7×5.0	4.20 to 4.70	2.00 to 2.50	4.20 to 4.70

Automotive

(Unit: mm)

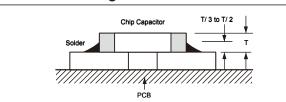
(E	Size IA Code)	L×W	а	b	C
10	05 (0603)	1.6×0.8	0.60 to 0.90	0.80 to 1.00	0.70 to 1.00
2	1 (0805)	2.0×1.25	0.90 to 1.20	0.80 to 1.20	0.90 to 1.40
31	16 (1206)	3.2×1.6	1.40 to 1.90	1.00 to 1.30	1.30 to 1.80

Arrays

(Unit: mm)

	а	b	С	d
F12 (0508)	0.5	0.5	0.3	0.5
D11 (0405)	0.69	0.28	0.3	0.64

Ideal Solder Height



Item	Not recommended example	Recommended example/ Separated by solder
Multiple parts mount		Solder resist
Mount with leaded parts	Leaded parts	Solder resist Leaded parts
Wire soldering after mounting	Soldering iron Wire	Solder resist
Overview	Solder resist	Solder resist

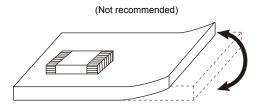
Multilayer Ceramic Chip Capacitors Surface Mounting Information

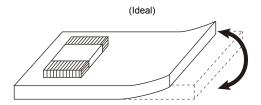


Mounting Design

The chip could crack if the PCB warps during processing after the chip has been soldered.

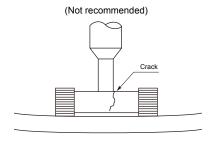
Recommended chip position on PCB to minimize stress from PCB warpage

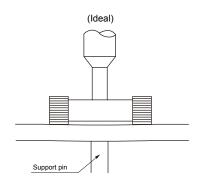




Actual Mounting

- 1) If the position of the vacuum nozzle is too low, a large force may be applied to the chip capacitor during mounting, resulting in cracking.
- 2) During mounting, set the nozzle pressure to a static load of 100 to 300 gf.
- 3) To minimize the shock of the vaccum nozzle, provide a support pin on the back of the PCB to minimize PCB flexture.





- 4) Bottom position of pick up nozzle should be adjusted to the top surface of a substrate which camber is corrected.
- 5) To reduce the possibility of chipping and cracks, minimize vibration to chips stored in a bulk case.
- 6) The discharge pressure must be adjusted to the part size. Verify the pressure during setup to avoid fracturing or cracking the chips capacitors.

Resin Mold

- 1) If a large amount of resin is used for molding the chip, cracks may occur due to contraction stress during curing. To avoid such cracks, use a low shrinkage resin.
- 2) The insulation resistance of the chip will degrade due to moisture absorption. Use a low moisture absorption resin.
- 3) Check carefully that the resin does not generate a decomposition gas or reaction gas during the curing process or during normal storage. Such gases may crack the chip capacitor or damage the device itself.

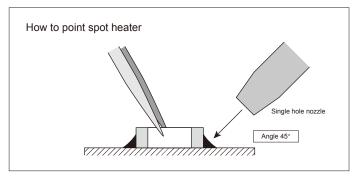
Multilayer Ceramic Chip Capacitors Surface Mounting Information

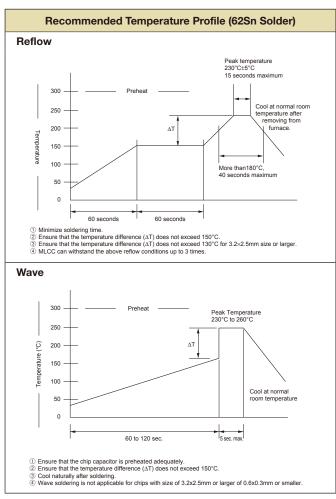


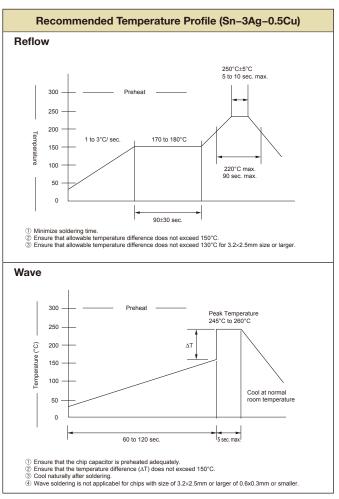
Soldering Method

- 1) Ceramic is easily damaged by rapid heating or cooling. If some heat shock is unavoidable, preheat enough to limit the temperature difference (Delta T) to within 130 degree Celsius.
- 2) The product size 1.0×0.5mm to 3.2×1.6mm can be used in reflow and wave soldering, and the product size of bigger than 3.2×1.6mm, or smaller than 1.0×0.5mm, and capacitor arrays can be used in reflow.
 - Circuit shortage and smoking can be created by using capacitors which are used neglecting the above caution.
- 3) Please see our recommended soldering conditions.
- 4) In case of using Sn-Zn Solder, please contact us in advance.
- 5) The following condition is recommended for spot heater application.
- · Recommended spot heater condition

Item Condition		
Distance	5mm min.	
Angle	45°	
Projection Temp.	400°C max.	
Flow rate	Set at the minimum	
Nozzle diameter	2φ to 4φ (Single hole type)	
Application time	10 sec. max. (1206 and smaller) 30 sec.max. (1210 and larger)	







Sodering iron

1) Temperature of iron chip 1206 and smaller 350°C max. 5) Cautions

> 1210 and larger 280°C max. 80W max.

2) Wattage

3) Tip shape of soldering iron

4) Soldering Time

\$3.0mm max. 3 sec. max.

a) Pre-heating is necessary rapid heating must be avoided.

Delta T≤150°C

- b) Avoid direct touching to capacitors.
- c) Avoid rapid cooling after soldering. Natural cooling is recommended.
- *Consult as if it is difficult to keep the temperature 280°C max. for 1210 and larger MLCC'S.

Multilayer Ceramic Chip Capacitors Precautions



Circuit Design

- Once application and assembly environments have been checked, the capacitor may be used in conformance with the rating and
 performance which are provided in both the catalog and the specifications. Use exceeding that which is specified may result in inferior
 performance or cause a short, open, smoking, or flaming to occur, etc.
- 2. Please consult the manufacturer in advance when the capacitor is used in devices such as: devices which deal with human life, i.e. medical devices; devices which are highly public orientated; and devices which demand a high standard of liability.
 Accident or malfunction of devices such as medical devices, space equipment and devices having to do with atomic power could generate grave consequence with respect to human lives or, possibly, a portion of the public. Capacitors used in these devices may require high reliability design different from that of general purpose capacitors.
- 3. Please use the capacitors in conformance with the operating temperature provided in both the catalog and the specifications.

 Be especially cautious not to exceed the maximum temperature. In the situation the maximum temperature set forth in both the catalog and specifications is exceeded, the capacitor's insulation resistance may deteriorate, power may suddenly surge and short-circuit may occur.

 The capacitor has a loss, and may self-heat due to equivalent series resistance when alternating electric current is passed therethrough. As this effect becomes especially pronounced in high frequency circuits, please exercise caution.

 When using the capacitor in a (self-heating) circuit, please make sure the surface of the capacitor remains under the maximum temperature for usage. Also, please make certain temperature rises remain below 20°C.
- 4. Please keep voltage under the rated voltage which is applied to the capacitor. Also, please make certain the peak voltage remains below the rated voltage when AC voltage is super-imposed to the DC voltage.
 In the situation where AC or pulse voltage is employed, ensure average peak voltage does not exceed the rated voltage.
 Exceeding the rated voltage provided in both catalog and specifications may lead to defective withstanding voltage or, in worst case situations, may cause the capacitor to smoke or flame.
- 5. When the capacitor is to be employed in a circuit in which there is continuous application of a high frequency voltage or a steep pulse voltage, even though it is within the rated voltage, please inquire to the manufacturer.
 In the situation the capacitor is to be employed using a high frequency AC voltage or a extremely fast rising pulse voltage, even though it is within the rated voltage, it is possible capacitor reliability will deteriorate.
- 6. It is a common phenomenon of high-dielectric products to have a deteriorated amount of static electricity due to the application of DC voltage.

 Due caution is necessary as the degree of deterioration varies depending on the quality of capacitor materials, capacity, as well as the load voltage at the time of operation.
- 7. Do not use the capacitor in an environment where it might easily exceed the respective provisions concerning shock and vibration specified in the catalog and specifications.
 In addition, it is a common piezo phenomenon of high dielectric products to have some voltage due to vibration or to have noise due to voltage change. Please contact sales in such case.
- 8. If the electrostatic capacity value of the delivered capacitor is within the specified tolerance, please consider this when designing the respective product in order that the assembled product function appropriately.
- 9. Please contact us upon using conductive adhesives.

Storage

- 1. If the component is stored in minimal packaging (a heat–sealed or chuck–type plastic bag), the bag should be kept closed. Once the bag has been opened, reseal it or store it in a desiccator.
- 2. Keep storage place temperature +5 to +35 degree C, humidity 45 to 70% RH.
- 3. The storage atmosphere must be free of gas containing sulfur and chlorine. Also, avoid exposing the product to saline moisture. If the product is exposed to such atmospheres, the terminals will oxidize and solderability will be effected.
- 4. Precautions 1) to 3) apply to chip capacitors packaged in carrier tapes and bulk cases.
- 5. The solderability is assured for 12 months from our shipping date (six months for silver palladium) if the above storage precautions are followed.
- 6. Chip capacitors may crack if exposed to hydrogen (H2) gas while sealed or if coated with silicon, which generates hydrogen gas.

Safety application guideline and detailed information of electrical properties are also provided in Kyocera home page; URL: http://www.kyocera.co.jp/electronic/